

# Contents

<b>1</b>	<b>Introduction</b>	1
	References	3
<b>2</b>	<b>Electronic and Transport Properties of Graphene</b>	5
2.1	Introduction	5
2.2	Graphene and Dirac Fermions	6
2.2.1	Graphene	6
2.2.2	Low-Energy Dispersion	9
2.3	Electronic and Transport Properties of Disordered Graphene	12
2.4	Spin Transport in Graphene	20
2.4.1	Spin-Orbit Coupling in Graphene	20
2.4.2	Spin Transport in Graphene	27
	References	32
<b>3</b>	<b>The Real Space Order <math>O(N)</math> Transport Formalism</b>	35
3.1	Electrical Transport Formalism	35
3.1.1	Electrical Resistivity and Conductivity	35
3.1.2	Semiclassical Approach	36
3.1.3	The Kubo-Greenwood Formula	40
3.1.4	Three Transport Regimes	44
3.1.5	The Kubo Formalism in Real Space	47
3.2	Spin Transport Formalism	49
3.2.1	Wavefunction and Random Phase State with Spin	50
3.2.2	Spin Polarization	51
3.2.3	Technical Details	53
	References	54
<b>4</b>	<b>Transport in Disordered Graphene</b>	55
4.1	Transport Properties of Graphene with Vacancies	55
4.1.1	Introduction	55
4.1.2	Zero-Energy Modes and Transport Properties	57

4.2	Charge Transport in Poly-G. . . . .	65
4.2.1	Introduction . . . . .	65
4.2.2	Structure and Morphology of GGBs. . . . .	66
4.2.3	Methods of Observing GGBs . . . . .	69
4.2.4	Transport Properties of Intrinsic Poly-G by Simulation . . . . .	73
4.2.5	Measurement of Electrical Transport Across GGBs . . . . .	80
4.2.6	Manipulation of GGBs with Functional Groups . . . . .	87
4.2.7	Challenges and Opportunities . . . . .	93
4.3	Impact of Graphene Polycrystallinity on the Performance of Graphene Field-Effect Transistors. . . . .	94
4.3.1	Introduction . . . . .	94
4.3.2	Poly-G Effect on the Gate Electrostatics and I-V Characteristics of GFETs . . . . .	95
4.4	Transport Properties of Amorphous Graphene . . . . .	101
4.4.1	Introduction . . . . .	101
4.4.2	Models of Amorphous Graphene . . . . .	102
4.4.3	Electronic Properties. . . . .	104
	References . . . . .	108
5	<b>Spin Transport in Disordered Graphene</b> . . . . .	115
5.1	Spin Transport in Graphene: Pseudospin Driven Spin Relaxation Mechanism . . . . .	115
5.1.1	Introduction . . . . .	115
5.1.2	Spin Relaxation in Gold-Decorated Graphene . . . . .	117
5.1.3	Further Discussion . . . . .	124
5.2	Quantum Spin Hall Effect. . . . .	130
5.2.1	Introduction . . . . .	130
5.2.2	Adatom Clustering Effect on QSHE. . . . .	131
	References . . . . .	137
6	<b>Conclusions</b> . . . . .	141
	<b>Appendix A: Time Evolution of the Wave Packet.</b> . . . . .	143
	<b>Appendix B: Lanczos Method</b> . . . . .	147
	<b>Curriculum Vitae</b> . . . . .	151



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